

VOLTAGE RANGE: 150 - 200V

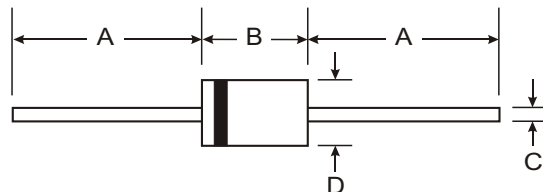
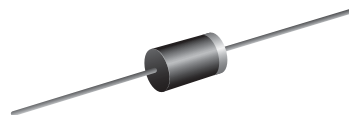
CURRENT: 1.0 A

Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications

Mechanical Data

- Case: DO-41, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-41		
Dim	Min	Max
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SB1150	SB1200	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	150	200	V
Maximum RMS voltage	V _{RMS}	105	140	V
Maximum DC blocking voltage	V _{DC}	150	200	V
Maximum average forward rectified current 0.375”(9.5mm) lead length(see fig.1)	I _(AV)	1.0		A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	40.0		A
Maximum instantaneous forward voltage at 1.0A	V _F	0.85	0.95	
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =100°C	I _R	0.2		mA
		2.0		
Typical junction capacitance (NOTE 1)	C _J	80		pF
Typical thermal resistance (NOTE 2)	R _{θJA}	50.0		°C/W
Operating junction temperature range	T _J	-65 to +150		°C
Storage temperature range	T _{STG}	-65 to +150		°C

Note:1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length,P.C.B. mounted

RATINGS AND CHARACTERISTIC CURVES SB1150 THRU SB1200

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE

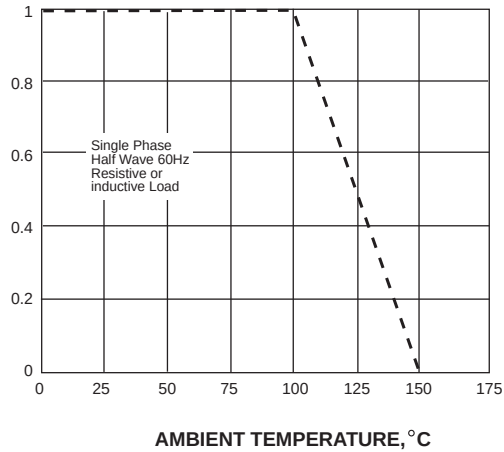


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

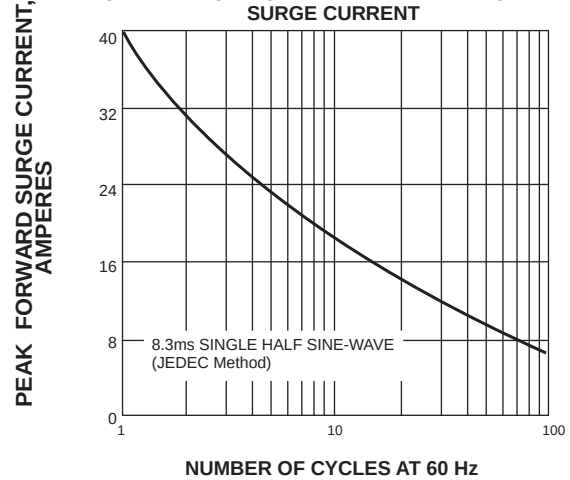


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

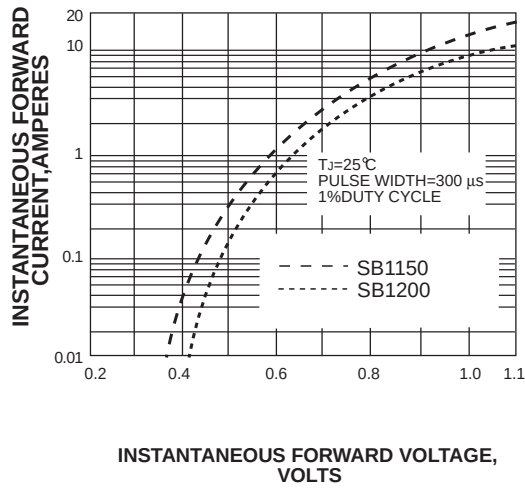


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

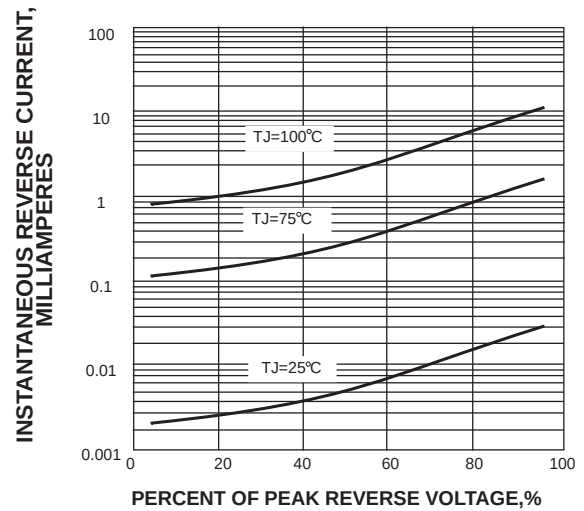


FIG. 5-TYPICAL JUNCTION CAPACITANCE

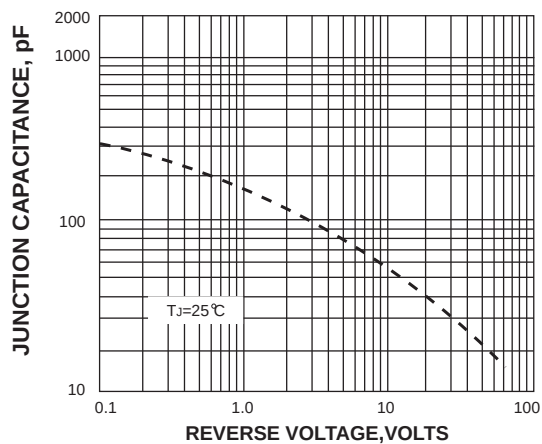


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

